

# Product/process change notification

## PCN N° 2022-226-A

Dear customer,

Please find attached our Infineon Technologies AG PCN:

Introduction of an additional wafer production at Infineon Technologies (Kulim) Sdn. Bhd., Kulim, Malaysia for several CIPOS™ Mini products

Important information for your attention:

- Please respond to this PCN by indicating your decision on the approval form, sign it and return to your sales partner before 2023-05-12
- Infineon aligns with the widely recognized JEDEC STANDARD "JESD46", which stipulates: "Lack of acknowledgement of the PCN within 30 days constitutes acceptance of the change."

Your prompt reply will help Infineon to assure a smooth and well-executed transition. If Infineon does not hear from your side by the due date, we will assume your full acceptance to this proposed change and its implementation.

Your attention and response to this matter is greatly appreciated.

Management Board Jochen Hanebeck (CEO), Constanze Hufenbecher, Dr. Sven Schneider, Andreas Urschitz, Dr. Rutger Wijburg
Registered office Neubiberg Commercial register Amtsgericht München HRB 126492



## **Product/process change notification**

## PCN N° 2022-226-A

▶ Products affected

Please refer to attached affected product list "pcn\_2022-226-A\_[customer-no].pdf"

**▶** Detailed change information

Subject

Introduction of an additional wafer production site.

Reason

Expansion of wafer production to assure continuity of supply and enable flexible manufacturing.

Description

<u>Old</u>

■ Infineon Technologies Austria AG, Villach, Austria <u>New</u>

Infineon Technologies
 Austria AG, Villach, Austria

and

Infineon Technologies (Kulim) Sdn. Bhd., Kulim, Malaysia

▶ Product identification

Wafer production and probe site

Internal traceability assured via lot code and development code. External traceability assured via Product Bar Code Label / Lot Code

Impact of change

No impact on electrical performance. Quality and reliability verified by qualification. There is no change in form, fit and function.

Attachments

"pcn\_2022-226-A\_[customer-no].pdf" a

affected product list

Time schedule

Final qualification report

on request

First samples available

on request

Intended start of delivery

2023-07-10

If you have any questions, please do not hesitate to contact your local sales office.

#### RESTRICTED

## **Qualification Test Report**



PCN No: 2022-226-A Date: 2023-03-24

Title: Introduction of an additional wafer production at Infineon Technologies (Kulim) Sdn. Bhd., Kulim, Malaysia for several CIPOS™ Mini products

Reason for choosing the following test vehicles:

IGCM04G60HA 4A, Small IGBT RCD1 chip group

IGCM20F60GA 20A, Large IGBT RCD1 chip group

IM521-X6A 10A, Mid IGBT RCD1(RCDF) chip group

Scope of qualification: PL59 IPM products with IGBT3 600V RC-D1 from Kulim -All IGCMxxx60xx (CIPOS  $^{TM}$  Mini) -IM521-X6A (CIPOS  $^{TM}$  Mini)

Assessment of Q-Results: All reliability tests including IPI & ESD passed qualification required for Tx9 of RCD-1 IGBT3 KUL transfer

Stress test	Abbreviation	Test conditions	Readout	IGCM04G60HA (Lot1)	IGCM20F60GA (Lot2)	IM521-X6A (Lot3)
				fails / stressed	fails / stressed	fails / stressed
Initial IPI	IPI	Physical inspection	T0	Pass	Pass	Pass
Temperature Cycling JESD22-A104	тс	with preconditioning Ta = -40°C ~ 125°C	200 x 500 x 1000 x	0 / 22 0 / 22 0 / 22	0 / 22 0 / 22 0 / 22	0/22 0/22 0/22
	IPI	Physical inspection	after 1000x	Pass	Pass	Pass
Unbiased Temperature/Humidity JESD22-A118	UHAST	with preconditioning Ta = 130°C, RH = 85%	96 h	0 / 22	0 / 22	0/22
	IPI	Physical inspection	after 96h	Pass	Pass	Pass
High Temperature Storage JESD22-A103	нтѕ	Ta = 125 °C	168 h 500 h 1000 h	0/22 0/22 0/22	0/22 0/22 0/22	0/22 0/22 0/22
	IPI	Physical inspection	after 1000h	Pass	Pass	Pass
High Voltage High Humidity, High Temperature Reverse Bias - Low Side JESD22-A101	THB_LS	Ta = 85°C RH = 85% VCE =80 V	168 h 500 h 1000 h	0/11 0/11 0/11	0/11 0/11 0/11	0/11 0/11 0/11
High Voltage High Humidity, High Temperature Reverse Bias - High Side JESD22-A101	ТНВ_НS	Ta = 85°C RH = 85% VCE =80 V	168 h 500 h 1000 h	0/11 0/11 0/11	0/11 0/11 0/11	0/11 0/11 0/11
High Temperature Reverse Bias - Low Side JESD22-A108	HTRB_LS	Tjmax <=150°C VCE = 480 V	168 h 500 h 1000 h	0/11 0/11 0/11	0/11 0/11 0/11	0/11 0/11 0/11
High Temperature Reverse Bias - High Side JESD22-A108	HTRB_HS	Tjmax <=150°C VCE = 480 V	168 h 500 h 1000 h	0/11 0/11 0/11	0/11 0/11 0/11	0/11 0/11 0/11
Intermittent Operational Life MIL-STD-750 Method 1037	IOL	with preconditioning Delta Tj = 100 °C	5000 x 10000 x	0 / 12 0 / 12	0 / 12 0 / 12	0/12 0/12
ESD Characterization - HBM ANSI/ESDA/JEDEC JS-001-2017	ESD HBM	Pulse interval = 1sec(Domain), 10sec(Matrix), 0.3sec(I/O) Discharge option = Yes Polarity = +/-	2000V 2250V 2500V 3000V	0/9 0/9 0/9 0/9	0/9 0/9 0/9 0/9	0/9 0/9 0/9 0/9
ESD Characterization - CDM ANSI/ESDA/JEDEC JS-002-2018	ESD CDM	3x pulses	500V 750V 1000V	0/3 0/3 0/3	0/3 0/3 0/3	0/3 0/3 0/3

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## Affected products sold to FUTURE ELECTRONICS LTD. (4049887)

Sales name	SP number	OPN	Package	Customer part number
IGCM04F60GA	SP001246994	IGCM04F60GAXKMA1	PG-MDIP-24-12	IGCM04F60GAXKMA1
IGCM06F60GA	SP001247004	IGCM06F60GAXKMA1	PG-MDIP-24-12	IGCM06F60GAXKMA1
IGCM10F60GA	SP001247016	IGCM10F60GAXKMA1	PG-MDIP-24-12	IGCM10F60GAXKMA1
IGCM15F60GA	SP001247022	IGCM15F60GAXKMA1	PG-MDIP-24-12	IGCM15F60GAXKMA1